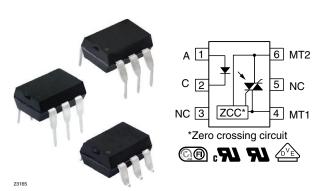
COMPLIANT



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# Optocoupler, Phototriac Output, Zero Crossing, High dV/dt, Low Input Current



## **LINKS TO ADDITIONAL RESOURCES**













#### **DESCRIPTION**

The VO4154 and VO4156 consists of a GaAs IRLED optically coupled to a photosensitive zero crossing TRIAC packaged in a DIP-6 package.

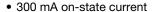
High input sensitivity is achieved by using an emitter follower phototransistor and a cascaded SCR predriver resulting in an LED trigger current of 1.6 mA for bin D, 2 mA for bin H, and 3 mA for bin M.

The phototriac zero crossing family uses a proprietary dV/dt clamp resulting in a static dV/dt of greater than 5 kV/ $\mu$ s.

The VO4154 and VO4156 isolates low-voltage logic from 120  $V_{AC}$ , 240  $V_{AC}$ , and 380  $V_{AC}$  lines to control resistive, inductive, or capacitive loads including motors, solenoids, high current thyristors or TRIAC and relays.

## **FEATURES**

- High static dV/dt 5 kV/µs
- High input sensitivity I<sub>FT</sub> = 1.6 mA, 2 mA, and 3 mA



- · Zero voltage crossing detector
- 400 V and 600 V blocking voltage
- Isolation rated voltage 4420 V<sub>RMS</sub>
- Material categorization: for definitions of compliance please see <a href="https://www.vishav.com/doc?99912"><u>www.vishav.com/doc?99912</u></a>

## **APPLICATIONS**

- Solid-state relays
- Industrial controls
- Office equipment
- Consumer appliances

#### **AGENCY APPROVALS**

- UL1577
- cUL
- DIN EN 60747-5-5 (VDE 0884-5), available with option 1
- FIMKO

ORDERING INFORMATION	N				
V O 4 1 5		- X 0		EAND (	Option 6 Option 7
AGENCY CERTIFIED / PACKAGE	V <sub>DRM</sub> 400 V <sub>DRM</sub> 600				
AGENCI CENTIFIED / PACKAGE	TRIGGER CURRENT, I <sub>FT</sub> (mA)				
UL, cUL	1.6 3 1.6 2 3				

AGENCY CERTIFIED / PACKAGE	- Drivi				
AGENCY CERTIFIED / PACKAGE	TRIGGER CURRENT, I <sub>FT</sub> (mA)				
UL, cUL	1.6	3	1.6	2	3
DIP-6	-	-	-	VO4156H	-
DIP-6, 400 mil, option 6	-	-	-	VO4156H-X006	VO4156M-X006
SMD-6, option 7	VO4154D-X007T	VO4154M-X007T	VO4156D-X007T	VO4156H-X007T	VO4156M-X007T
UL, cUL, VDE	1.6	3	1.6	2	3
SMD-6, option 7	-	-	VO4156D-X017T	=	-

#### Notes

- Also available in tubes, do not put "T" to the end
- Additional options may be possible, please contact sales office

Rev. 2.0, 12-Oct-2020 **1** Document Number: 84797



<b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	PART	SYMBOL	VALUE	UNIT			
INPUT								
Reverse voltage			$V_{R}$	6	V			
Forward current			I <sub>F</sub>	60	mA			
Surge current			I <sub>FSM</sub>	2.5	Α			
Power dissipation			P <sub>diss</sub>	100	mW			
Derate from 25 °C				1.33	mW/°C			
OUTPUT	OUTPUT							
Peak off-state voltage		VO4154D/M	$V_{DRM}$	400	V			
reak oil-state voitage		VO4156D/H/M	$V_{DRM}$	600	V			
RMS on-state current			I <sub>TM</sub>	300	mA			
Total power dissipation			P <sub>diss</sub>	500	mW			
Derate from 25 °C				6.6	mW/°C			
COUPLER								
Storage temperature range			T <sub>stg</sub>	-55 to +150	°C			
Ambient temperature range			T <sub>amb</sub>	-55 to +100	°C			
Soldering temperature	Max. ≤ 10 s dip soldering ≥ 0.5 mm from case bottom		$T_{sld}$	260	°C			

#### Note

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
maximum ratings for extended periods of the time can adversely affect reliability

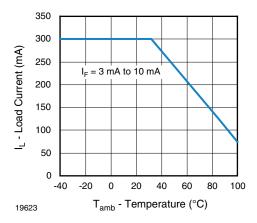


Fig. 1 - Recommended Operating Condition



THERMAL CHARACTERISTICS			
PARAMETER	SYMBOL	VALUE	UNIT
LED power dissipation	P <sub>diss</sub>	100	mW
Output power dissipation	P <sub>diss</sub>	500	mW
Maximum LED junction temperature	T <sub>jmax</sub> .	125	°C
Maximum output die junction temperature	T <sub>jmax</sub> .	125	°C
Thermal resistance, junction emitter to board	$\theta_{JEB}$	150	°C/W
Thermal resistance, junction emitter to case	$\theta_{JEC}$	139	°C/W
Thermal resistance, junction detector to board	$\theta_{JDB}$	78	°C/W
Thermal resistance, junction detector to case	$\theta_{JDC}$	103	°C/W
Thermal resistance, junction emitter to junction detector	$\theta_{JED}$	496	°C/W
Thermal resistance, case to ambient	$\theta_{CA}$	3563	°C/W

#### Note

The thermal characteristics table above were measured at 25 °C and the thermal model is represented in the thermal network below. Each
resistance value given in this model can be used to calculate the temperatures at each node for a given operating condition. The thermal
resistance from board to ambient will be dependent on the type of PCB, layout and thickness of copper traces. For a detailed explanation
of the thermal model, please reference Vishay's Thermal Characteristics of Optocouplers application note

<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT							
Forward voltage	I <sub>F</sub> = 10 mA		$V_{F}$	-	1.2	1.4	V
Reverse current	V <sub>R</sub> = 6 V		I <sub>R</sub>	-	0.1	10	μΑ
Input capacitance	$V_F = 0 V, f = 1 MHz$		Cı	-	25	-	pF
OUTPUT							
Repetitive peak off-state voltage	I <sub>DRM</sub> = 100 μA	VO4154D/M	$V_{DRM}$	400	-	-	٧
nepetitive peak oil-state voitage	IDRM = 100 μA	VO4156D/H/M	$V_{DRM}$	600	-	-	٧
Off-state current	$V_D = V_{DRM}$ , $I_F = 0$ A		I <sub>DRM</sub>	-	-	100	μΑ
On-state voltage	$I_{T} = 300 \text{ mA}$		$V_{TM}$	-	-	3	V
On-state current	$PF = 1, V_{T(RMS)} = 1.7 V$		I <sub>TM</sub>	-	-	300	mA
Off-state current in inhibit state	I <sub>F</sub> = 2 mA, V <sub>DRM</sub>		I <sub>DINH</sub>	-	-	200	μA
Holding current			I <sub>H</sub>	-	-	500	μΑ
Zero cross inhibit voltage	$I_F = \text{rated } I_{FT}$		$V_{IH}$	-	-	20	V
Critical rate of rise of off-state voltage	V <sub>D</sub> = 0.67 V <sub>DRM</sub> , T <sub>J</sub> = 25 °C		dV/dt <sub>cr</sub>	5000	-	-	V/µs
Critical rate of rise of on-state			dV/dt <sub>cr</sub>	8	-	-	A/µs
COUPLER							
		VO4154D	I <sub>FT</sub>	-	-	1.6	mA
		VO4154M	I <sub>FT</sub>	-	-	3	mA
LED trigger current, current required to latch output	$V_D = 3 V$	VO4156D	I <sub>FT</sub>	-	-	1.6	mA
current required to later output		VO4156H	I <sub>FT</sub>	-	-	2	mA
		VO4156M	I <sub>FT</sub>	-	-	3	mA
Common mode coupling capacitance			ССМ	=	0.01	-	pF
Capacitance (input to output)	f = 1 MHz, V <sub>IO</sub> = 0 V		C <sub>IO</sub>	-	0.8	-	pF

#### Note

Minimum and maximum values were tested requirements. Typical values are characteristics of the device and are the result of engineering
evaluations. Typical values are for information only and are not part of the testing requirements



SAFETY AND INSULATION RATINGS						
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT		
Climatic classification	According to IEC 68 part 1		55/100/21			
Pollution degree	According to DIN VDE 0109		2			
Comparative tracking index	Insulation group IIIa	CTI	175			
Maximum rated withstanding isolation voltage	According to UL1577, t = 1 min	V <sub>ISO</sub>	4420	V <sub>RMS</sub>		
Maximum transient isolation voltage	According to DIN EN 60747-5-5	V <sub>IOTM</sub>	8000	V <sub>peak</sub>		
Maximum repetitive peak isolation voltage	According to DIN EN 60747-5-5	V <sub>IORM</sub>	890	V <sub>peak</sub>		
Isolation resistance	T <sub>amb</sub> = 25 °C, V <sub>IO</sub> = 500 V	R <sub>IO</sub>	≥ 10 <sup>12</sup>	Ω		
	T <sub>amb</sub> = 100 °C, V <sub>IO</sub> = 500 V	R <sub>IO</sub>	≥ 10 <sup>11</sup>	Ω		
Output safety power		P <sub>SO</sub>	500	mW		
Input safety current		I <sub>SI</sub>	250	mA		
Input safety temperature		T <sub>S</sub>	175	°C		
Creepage distance	DIP-6		≥ 7	mm		
Clearance distance	- DIP-6		≥ 7	mm		
Creepage distance	DIP-6, 400 mil, option 6		≥ 8	mm		
Clearance distance	DIF-6, 400 IIIII, Option 6		≥ 8	mm		
Creepage distance	SMD 6 aption 7		≥ 7	mm		
Clearance distance	SMD-6, option 7		≥ 7	mm		
Insulation thickness		DTI	≥ 0.4	mm		

#### Note

# TYPICAL CHARACTERISTICS (T<sub>amb</sub> = 25 °C, unless otherwise specified)

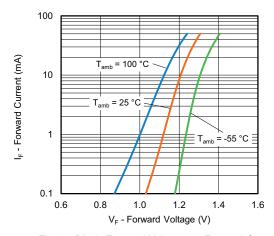


Fig. 2 - Diode Forward Voltage vs. Forward Current

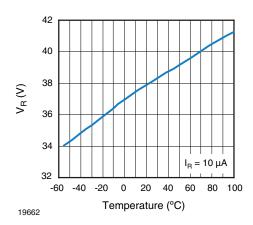


Fig. 3 - Diode Reverse Voltage vs. Temperature

As per IEC 60747-5-5, § 7.4.3.8.2, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with
the safety ratings shall be ensured by means of protective circuits

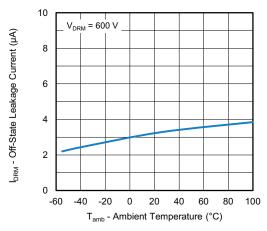


Fig. 4 - Leakage Current vs. Ambient Temperature

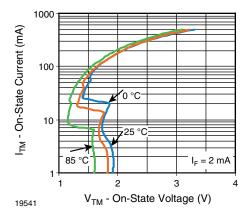


Fig. 5 - On-State Current vs. On-State Voltage

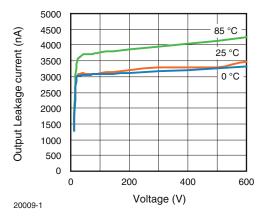


Fig. 6 - Output Off Current (Leakage) vs. Voltage

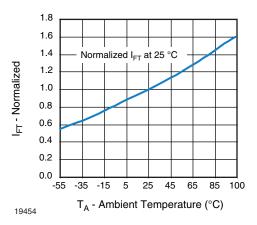


Fig. 7 - Normalized Trigger Input Current vs. Temperature

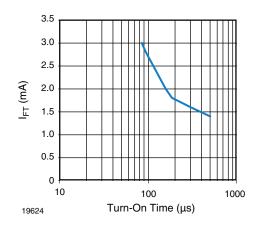


Fig. 8 - I<sub>FT</sub> (mA) vs. Turn-On Time (µs)

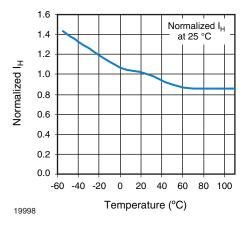


Fig. 9 - Normalized Holding Current vs. Temperature

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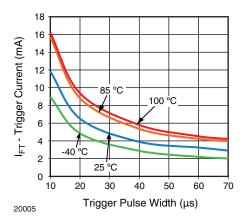
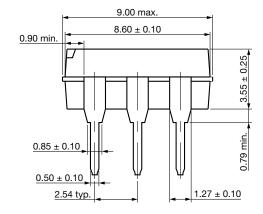
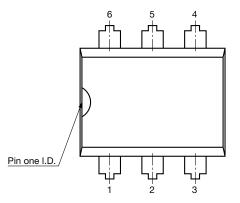


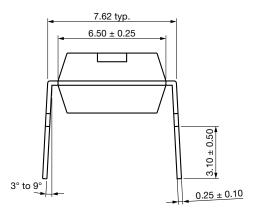
Fig. 10 - IFT vs. LED Pulse Width

## **PACKAGE DIMENSIONS**

#### DIP-6

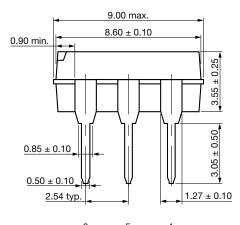


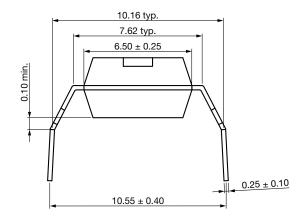


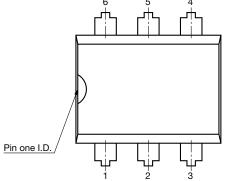




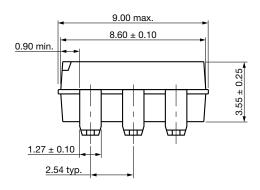
# DIP-6, Option 6

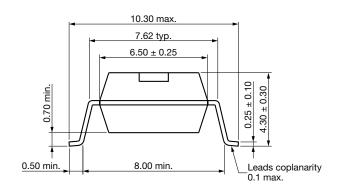


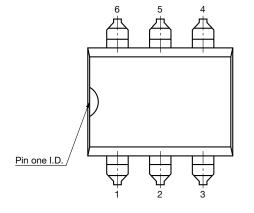


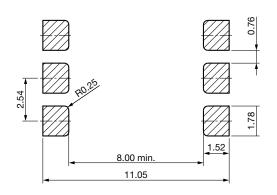


# SMD-6, Option 7









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## **PACKAGE MARKING**



Fig. 11 - Example of VO4156D-X017T



Fig. 12 - Example of VO4154D-X006

## **Notes**

- "YWW" is the date code marking (Y = year code, WW = week code)
- The VDE logo is only marked on option 1 parts
- Tape and reel suffix (T) is not part of the package marking

# **PACKING INFORMATION** (in millimeters)

## **Tube**

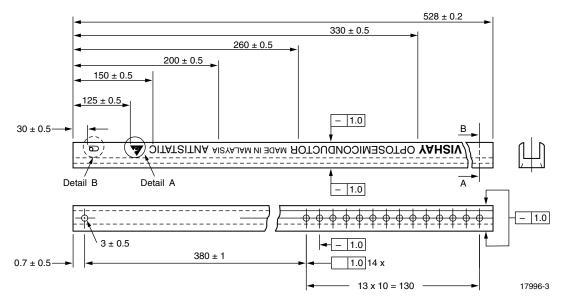


Fig. 13 - Shipping Tube Specifications for DIP-6 Packages

DEVICES PER TUBS						
TYPE	UNITS/TUBE	TUBES/BOX	UNITS/BOX			
DIP-6	50	40	2000			
DIP-6, option 6	50	40	2000			

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DIP-6

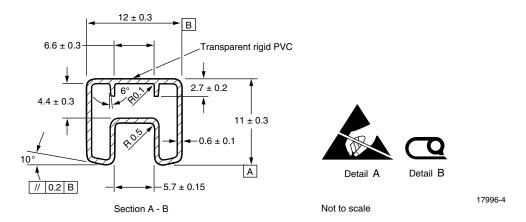


Fig. 14 - Tube Shipping Medium

## DIP-6, Option 6

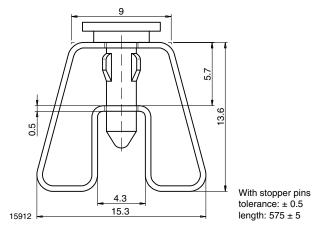


Fig. 15 - Tube Shipping Medium

## **Tape and Reel**

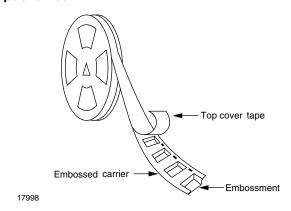


Fig. 16 - Tape and Reel Shipping Medium

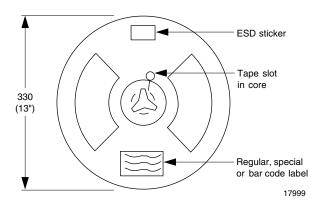


Fig. 17 - Tape and Reel Shipping Medium

# SMD-6, Option 7

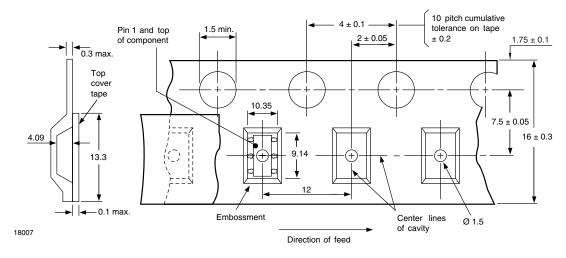


Fig. 18 - Tape and Reel Packing (1000 pieces on reel)

## **SOLDER PROFILES**

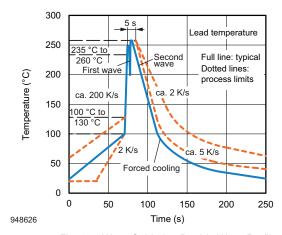


Fig. 19 - Wave Soldering Double Wave Profile According to J-STD-020 for DIP Devices

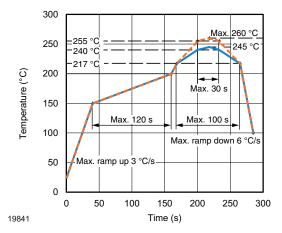


Fig. 20 - Lead (Pb)-free Reflow Solder Profile According to J-STD-020 for SMD Devices

# HANDLING AND STORAGE CONDITIONS

ESD level: HBM class 2 Floor life: unlimited

Conditions:  $T_{amb}$  < 30 °C, RH < 85 %

Moisture sensitivity level 1, according to J-STD-020

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